

**isc N-Channel MOSFET Transistor**
**IPA086N10N3, IIPA086N10N3**
**• FEATURES**

- Low drain-source on-resistance:  
 $R_{DS(on)} \leq 4.5m\Omega$  (max)
- Enhancement mode
- Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**• DESCRIPTION**

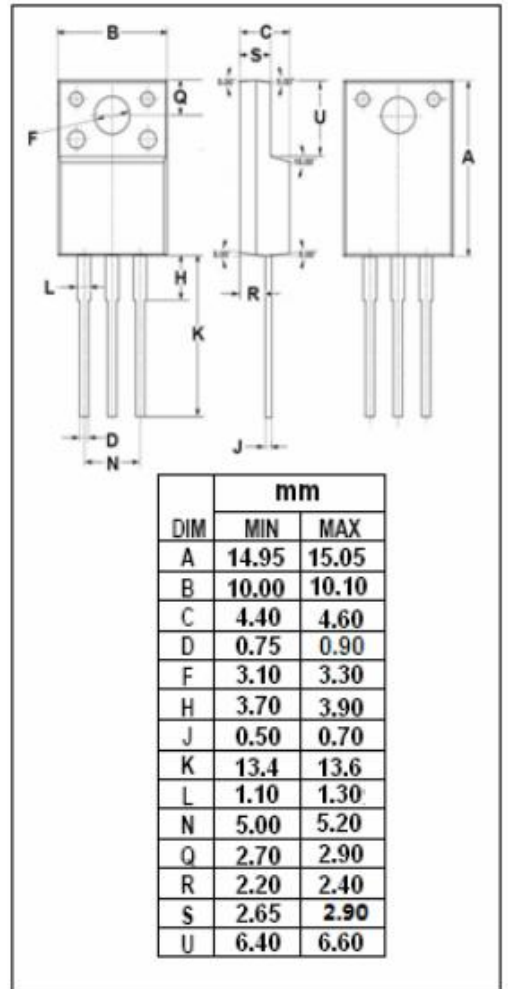
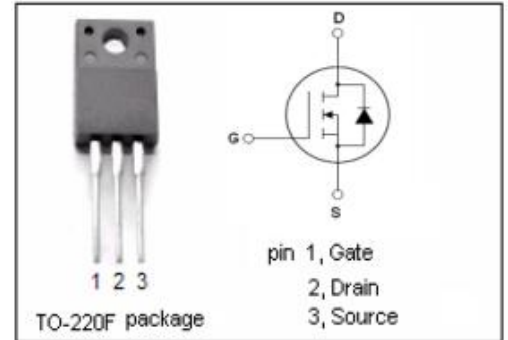
- Device for use in a wide variety of applications

**• ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ C$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DS}$	Drain-Source Voltage	100	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Drain Current-Continuous	64	A
$I_{DM}$	Drain Current-Single Pulsed	256	A
$P_D$	Total Dissipation @ $T_c=25^\circ C$	39	W
$T_j$	Max. Operating Junction Temperature	175	$^\circ C$
$T_{stg}$	Storage Temperature	-55~175	$^\circ C$

**• THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	3.8	$^\circ C/W$



**isc N-Channel MOSFET Transistor****IPA086N10N3,IIPA086N10N3****ELECTRICAL CHARACTERISTICS** $T_C=25^{\circ}\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V; I_D=1mA$	100			V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}; I_D=150\mu A$	2.0		3.8	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10V; I_D=64A$			4.5	$m\Omega$
$I_{GSS}$	Gate-Source Leakage Current	$V_{GS}=20V; V_{DS}=0V$			100	nA
$I_{DSS}$	Drain-Source Leakage Current	$V_{DS}=100V; V_{GS}=0V$			1	$\mu A$
$V_{SD}$	Diode forward voltage	$I_{DR}=64A, V_{GS}=0V$			1.0	V

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